SOD-123 Schottky Barrier Diodes

MMSD301T1G, SMMSD301T1G, MMSD701T1G, SMMSD701T1G,

The MMSD301T1, and MMSD701T1 devices are spin-offs of our popular MMBD301LT1, and MMBD701LT1 SOT-23 devices. They are designed for high-efficiency UHF and VHF detector applications. Readily available to many other fast switching RF and digital applications.

Features

- Extremely Low Minority Carrier Lifetime
- Very Low Capacitance
- Low Reverse Leakage
- AEC Qualified and PPAP Capable
- S Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant*

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Reverse Voltage MMSD301T1G, SMMSD301T1G MMSD701T1G, SMMSD701T1G	V _R	30 70	Vdc
Forward Current (DC) Continous	IF	200	mA
Forward Power Dissipation T _A = 25°C	P _F	225	mW
Junction Temperature	TJ	-55 to +125	°C
Storage Temperature Range	T _{stg}	-55 to +150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.



ON Semiconductor®

www.onsemi.com



SOD-123 CASE 425 STYLE 1



MARKING DIAGRAM



xx = Specific Device Code XT = MMSD301T1G SMMSD301T1G XH = MMSD701T1G

SMMSD70111G - Date Code

M = Date Code= Pb-Free Package

(Note: Microdot may be in either location)

ORDERING INFORMATION

Device	Package	Shipping [†]
MMSD301T1G	SOD-123 (Pb-Free)	3,000 / Tape & Reel
SMMSD301T1G	SOD-123 (Pb-Free)	3,000 / Tape & Reel
MMSD701T1G	SOD-123 (Pb-Free)	3,000 / Tape & Reel
SMMSD701T1G	SOD-123 (Pb-Free)	3,000 / Tape & Reel

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

^{*}For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

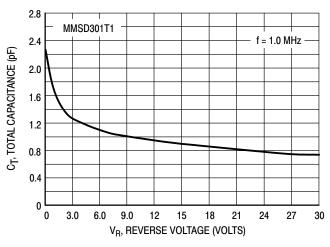
${\bf MMSD301T1G,\,SMMSD301T1G,\,MMSD701T1G,\,SMMSD701T1G,}$

ELECTRICAL CHARACTERISTICS ($T_A = 25^{\circ}C$ unless otherwise noted)

Characteristic	Symbol	Min	Тур	Max	Unit
Reverse Breakdown Voltage (I _R = 10 μA) MMSD301T1G, SMMSD301T1G	V _{(BR)R}	30	-	-	V
MMSD701T1G, SMMSD701T1G		70	-	_	
Diode Capacitance (V _B = 0 V, f = 1.0 MHz)	C _T				pF
MMSD301T1G, SMMSD301T1G MMSD701T1G, SMMSD701T1G		- -	0.9 0.5	1.5 1.0	
Total Capacitance	C _T				pF
(V _R = 15 V, f = 1.0 MHz) MMSD301T1G, SMMSD301T1G (V _R = 20 V, f = 1.0 MHz)		_	0.9	1.5	
MMSD701T1G, SMMSD701T1G		-	0.5	1.0	
Reverse Leakage	I _R				nAdc
$(V_R = 25 \text{ V})$ MMSD301T1G, SMMSD301T1G $(V_R = 35 \text{ V})$		-	13	200	
MMSD701T1G, SMMSD701T1G		-	9.0	200	
Forward Voltage (I _F = 1.0 mAdc)	V _F				Vdc
MMSD301T1G, SMMSD301T1G (I _F = 10 mA) (I _F = 1.0 mAdc)		-	0.38 0.52	0.45 0.6	
MMSD701T1G, SMMSD701T1G (I _F = 10 mA)		- -	0.42 0.7	0.5 1.0	

MMSD301T1G, SMMSD301T1G, MMSD701T1G, SMMSD701T1G,

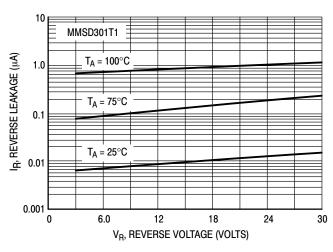
TYPICAL CHARACTERISTICS MMSD301T1G, SMMSD301T1G



500 MMSD301T1 WH 400 KRAKAUER METHOD KRAKAUER METHOD 100 100 100 20 30 40 50 60 70 80 90 100 15 FORWARD CURRENT (mA)

Figure 1. Total Capacitance

Figure 2. Minority Carrier Lifetime



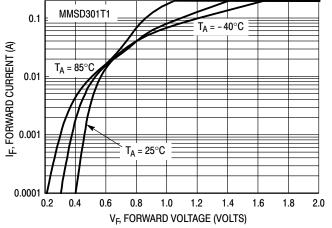


Figure 3. Reverse Leakage

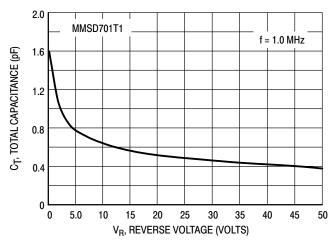
Figure 4. Forward Voltage

MMSD301T1G, SMMSD301T1G, MMSD701T1G, SMMSD701T1G,

TYPICAL CHARACTERISTICS MMSD701T1G, SMMSD701T1G

100

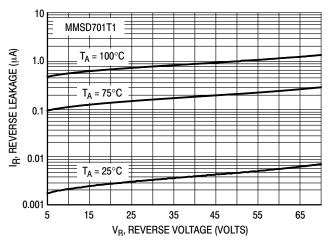
MMSD701T1



500 MMSD701T1 τ , MINORITY CARRIER LIFETIME (ps) 400 KRAKAUER METHOD 300 200 100 0 10 20 30 40 50 70 80 90 100 I_{F.} FORWARD CURRENT (mA)

Figure 5. Total Capacitance

Figure 6. Minority Carrier Lifetime



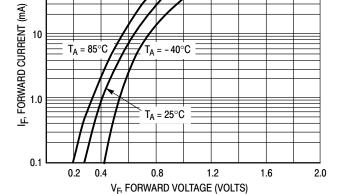


Figure 7. Reverse Leakage

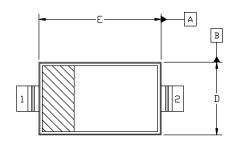
Figure 8. Forward Voltage



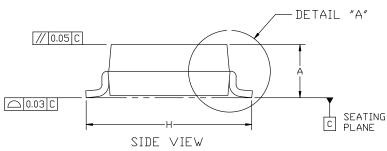


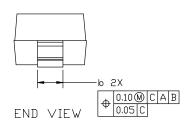
SOD-123 2L 1.60x2.69x1.16 **CASE 425 ISSUE H**

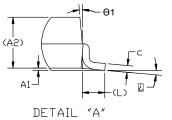
DATE 29 FEB 2024



TOP VIEW







NOTES:

- DIMENSION AND TOLERANCING PER ASME Y14.5M, 2018
- 2. CONTROLLING DIMENSION: MILLIMETERS

	MILLIMETER			
DIM	MIN.	N□M.	MAX.	
А	0.94	1.17	1.35	
A1	0.00	0.05	0.10	
A2	1.16 REF.			
b	0.51	0.61	0.71	
C	_	_	0.15	
D	1.40	1.60	1.80	
E	2.54	2.69	2.84	
Н	3.56	3.68	3,86	
L	0.25 REF.			
S	0°		10°	
θ1	0°		10°	



RECOMMENDED MOUNTING FOOTPRINT *For additional information on or Pb-Free strategy and soldering details, please download the DN Semiconductor Soldering and Mounting Techniques Reference manual SDLDERRM/D.

GENERIC MARKING DIAGRAM*



XXX = Specific Device Code

= Date Code

= Pb-Free Package

(Note: Microdot may be in either location)

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "■", may or may not be present. Some products may not follow the Generic Marking.

STYLE 1:
PIN 1. CATHODE
2. ANODE

DOCUMENT NUMBER:	98ASB42927B	Electronic versions are uncontrolled except when accessed directly from the Document Repository Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.		
DESCRIPTION:	SOD-123 2L 1.60x2.69x1.16		PAGE 1 OF 1	

onsemi and ONSEMI are trademarks of Semiconductor Components Industries, LLC dba onsemi or its subsidiaries in the United States and/or other countries. onsemi reserves the right to make changes without further notice to any products herein. onsemi makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does **onsemi** assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. **onsemi** does not convey any license under its patent rights nor the rights of others.

onsemi, Onsemi, and other names, marks, and brands are registered and/or common law trademarks of Semiconductor Components Industries, LLC dba "onsemi" or its affiliates and/or subsidiaries in the United States and/or other countries. onsemi owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of onsemi's product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. Onsemi reserves the right to make changes at any time to any products or information herein, without notice. The information herein is provided "as-is" and onsemi makes no warranty, representation or guarantee regarding the accuracy of the information, product features, availability, functionality, or suitability of its products for any particular purpose, nor does onsemi assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using onsemi products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by onsemi. "Typical" parameters which may be provided in onsemi data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. onsemi does not convey any license under any of its intellectual property rights nor the rights of others. onsemi products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA class 3 medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase

ADDITIONAL INFORMATION

TECHNICAL PUBLICATIONS:

 $\textbf{Technical Library:} \ \underline{www.onsemi.com/design/resources/technical-documentation}$

onsemi Website: www.onsemi.com

ONLINE SUPPORT: www.onsemi.com/support

For additional information, please contact your local Sales Representative at

www.onsemi.com/support/sales